

### PLASTIC SILICON RECTIFIER

VOLTAGE RANGE: 200 --- 400 V  
CURRENT: 1.5 A

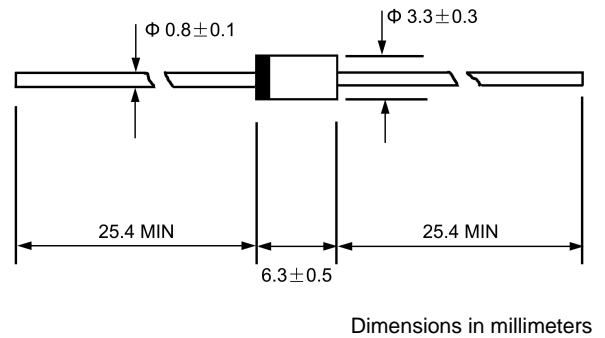
#### FEATURES

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with Freon, Alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

#### MECHANICAL DATA

- ◇ Case: JEDEC DO--15, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL- STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.014 ounces, 0.39 grams
- ◇ Mounting position: Any

#### DO - 15



#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

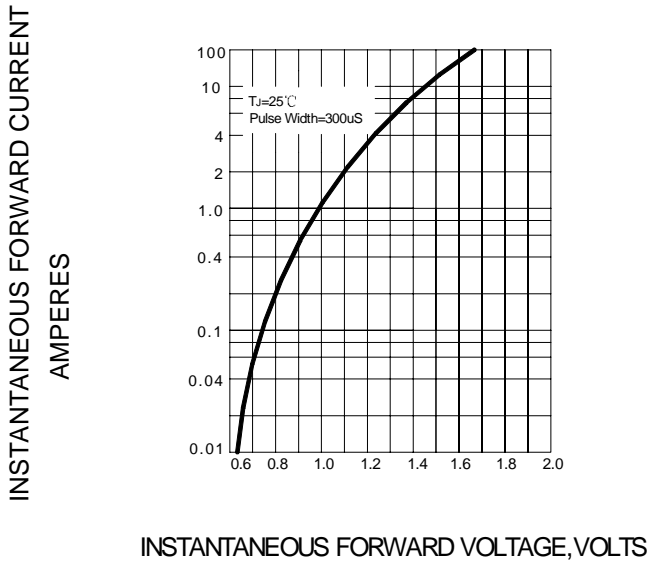
		ERC04 -02F	ERC04 -04F	UNITS
Maximum recurrent peak reverse voltage	$V_{RRM}$	200	400	V
Maximum RMS voltage	$V_{RMS}$	140	280	V
Maximum DC blocking voltage	$V_{DC}$	200	400	V
Maximum average forward rectified current 9.5mm lead length, @ $T_A=75^\circ C$	$I_{F(AV)}$	1.5		A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ C$	$I_{FSM}$	100.0		A
Maximum instantaneous forward voltage @ 1.5 A	$V_F$	1.1		V
Maximum reverse current @ $T_A=25^\circ C$ at rated DC blocking voltage @ $T_A=100^\circ C$	$I_R$	5.0	50.0	$\mu A$
Typical junction capacitance (Note1)	$C_J$	20		pF
Typical thermal resistance (Note2)	$R_{\theta JA}$	40		$^\circ C / W$
Operating junction temperature range	$T_J$	-55----+150		$^\circ C$
Storage temperature range	$T_{STG}$	-55----+150		$^\circ C$

NOTE: 1. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

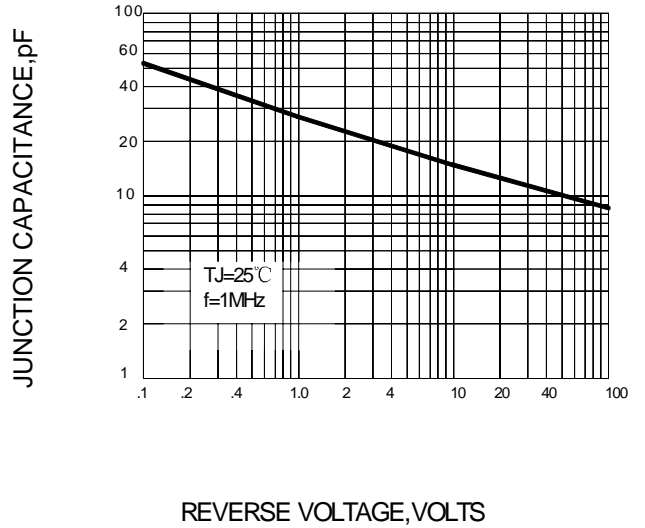
2. Thermal resistance from junction to ambient.

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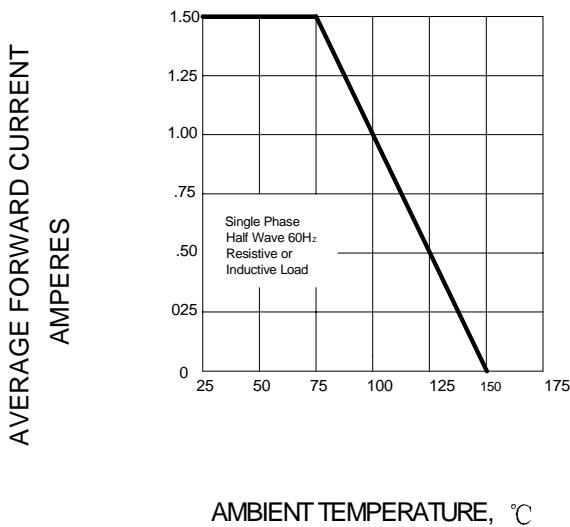
**FIG.1 – FORWARD CHARACTERISTIC**



**FIG.2 – JUNCTION CHARACTERISTICS**



**FIG.3 – CURRENT DERATING CURVE**



**FIG.4 – SURGE CAPABILITY**

